



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C		
30V	21.5mΩ @ V _{GS} = 10V	10A		
307	29mΩ @ V _{GS} = 4.5V	8A		

Description

This MOSFET has been designed to minimize the on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- **Power Management Functions**
- DC-DC Converters

Features and Benefits

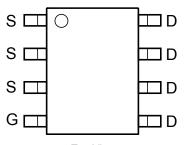
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

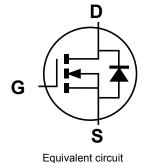
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.074 grams (approximate)







Top View Internal Schematic



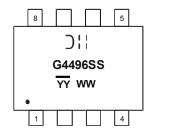
Ordering Information (Note 4 & 5)

Part Number	Compliance	Case	Packaging
DMG4496SSS-13	Standard	SO-8	2500 / Tape & Reel
DMG4496SSSQ-13	Automotive	SO-8	2500 / Tape & Reel

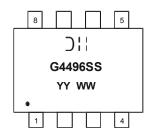
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Chengdu A/T Site



Shanghai A/T Site

);; = Manufacturer's Marking G4496SS = Product Type Marking Code

YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 13 = 2013) WW = Week (01 - 53)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test site) YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±25	V
Continuous Drain Current (Note 6) Steady $T_A = +25^{\circ}C$ State $T_A = +85^{\circ}C$		I _D	10 6	А	
Pulsed Drain Current (Note 7)			I _{DM}	60	A
Avalanche Current (Notes 7 & 8)			I _{AR}	8	А
Repetitive Avalanche Energy (Notes 7 & 8) L = 0.1mH			E _{AR}	3.2	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P_{D}	1.42	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6)	$R_{ heta JA}$	88.49	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

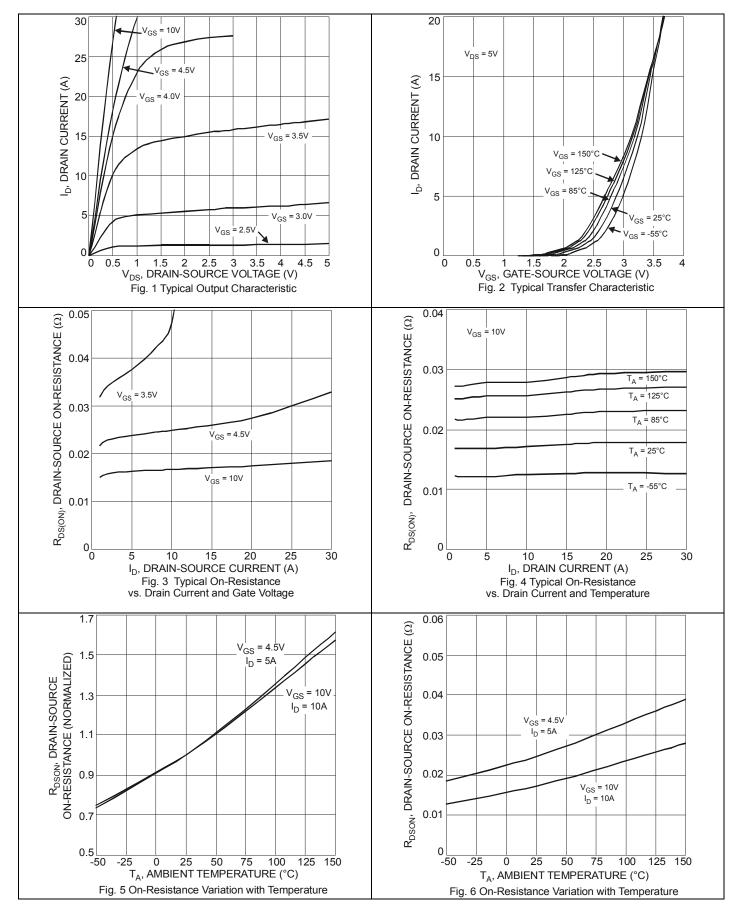
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 30V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(th)}	0.8	1.2	2.0	>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Б		16	21.5 29	mΩ	V _{GS} = 10V, I _D = 10A	
Static Dialii-Source Oil-Resistance	R _{DS(ON)}	_	22			V _{GS} = 4.5V, I _D = 7.5A	
Forward Transfer Admittance	Y _{fs}	_	11.7	_	S	V _{DS} = 5V, I _D = 10A	
Diode Forward Voltage	V _{SD}	_	0.70	1	V	V _{GS} = 0V, I _S = 1A	
DYNAMIC CHARACTERISTICS (Note 10)				•			
Input Capacitance	C _{iss}	_	493.5	_	pF	V _{DS} =15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	94.5	_			
Reverse Transfer Capacitance	C _{rss}	_	50.4	_	pF 1 - 1:0WH2		
Gate Resistance	Rg	_	2.86	_	Ω	V _{DS} =0V, V _{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} = 4.5V)	Q_g	_	4.7	_	nC	V _{DS} = 15V, V _{GS} = 4.5V, ID =10A	
Total Gate Charge (V _{GS} = 10V)	Q_g	_	10.2	_	IIC		
Gate-Source Charge	Q _{gs}	_	1.4	_	nC V _{DS} = 15V, V _{GS} = 10V, ID =10A		
Gate-Drain Charge	Q _{gd}	_	1.7	_	nC]	
Turn-On Delay Time	t _{D(on)}	_	4.76	_	ns	$V_{GS} = 10V, V_{Ds} = 15V,$ $R_G = 6\Omega, R_L = 15\Omega,$	
Turn-On Rise Time	tr	_	3.64	_	ns		
Turn-Off Delay Time	t _{D(off)}	_	19.5	_	ns		
Turn-Off Fall Time	t _f	_	4.9	_	ns		

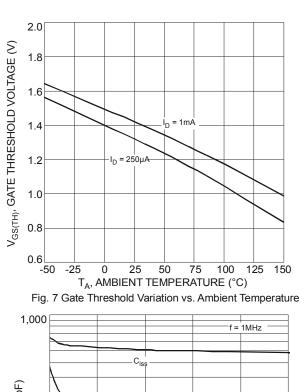
Notes:

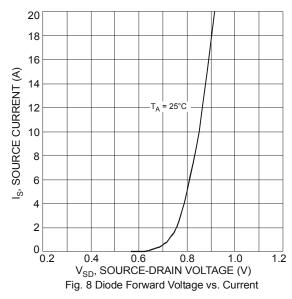
- 6. Device mounted on 1 in.² FR-4 board with 2oz. Copper, in a still air environment @ T_A = +25°C. The value in any given application depends on the user's specific board design.
 7. Repetitive rating, pulse width limited by junction temperature.
 8. I_{AR} and E_{AR} rating are based on low frequency and duty cycles to keep T_J = 25°C
 9. Short duration pulse test used to minimize self-heating effect.
 10. Guaranteed by design. Not subject to production testing.

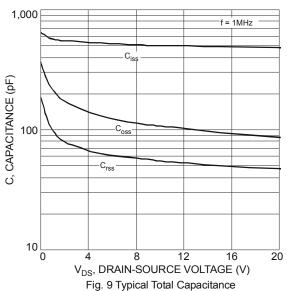


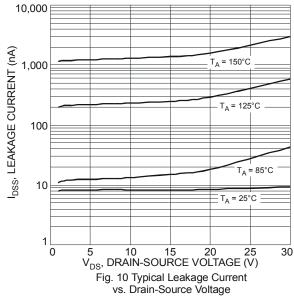












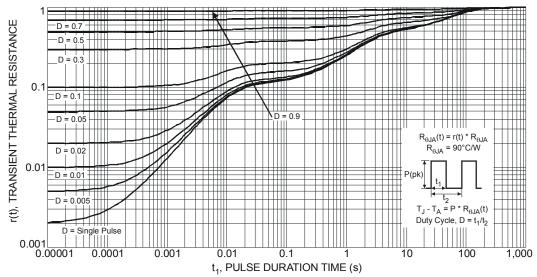
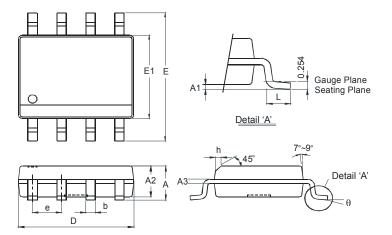


Fig. 11 Transient Thermal Response



Package Outline Dimensions

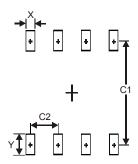
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SO-8				
Dim	Min	Max		
Α	1	1.75		
A1	0.10	0.20		
A2	1.30	1.50		
A3	0.15	0.25		
b	0.3	0.5		
D	4.85	4.95		
E	5.90	6.10		
E1	3.85	3.95		
е	1.27 Typ			
h	-	0.35		
L	0.62	0.82		
θ	0°	8°		
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27



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